

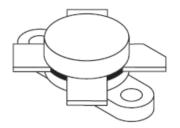
Rev. V1

#### **Description**

Designed primarily for high voltage applications as a high power linear amplifiers from 2 to 30 MHz. Ideal for marine and base station equipment.

- Specified 50 V, 30 MHz characteristics
   Output power = 250 W
   Minimum gain = 12 dB
   Efficiency = 45%
- Intermodulation distortion @ 250 W (PEP) - IMD = -30 dB (max.)
- 100% tested for load mismatch at all phase angles with 3:1 VSWR

### **Product Image**



### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{\sf CEO}$	50	Vdc
Collector-Base Voltage	$V_{CBO}$	100	Vdc
Emitter-Base Voltage	$V_{EBO}$	4	Vdc
Collector Current - Continuous	Ic	16	Adc
Withstand Current - 10 s	-	20	Adc
Total Device Dissipation @ Tc =25°C (1) Derate above 25°C	P <sub>D</sub>	290 1.67	Watts W/°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max.	Unit
Thermal Resistance, Junction to Case	$R_{\text{eJC}}$	0.6	°C/W

### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 200 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	_	_	Vdc
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 100 mAdc, V <sub>BE</sub> = 0)	V <sub>(BR)CES</sub>	100	_	_	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = 100 mAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	100	_	_	Vdc
Emitter-Base Breakdown Voltage (I <sub>E</sub> = 10 mAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	4	_	_	Vdc

(continued)

Note:

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<sup>1.</sup> PD is a measurement reflecting short term maximum condition. See SOAR curve for operating conditions.

## **MRF448A**



# The RF Line NPN Silicon Power Transistor 250 W, 30 MHz, 50 V

Rev. V1

### **ELECTRICAL CHARACTERISTICS - continued** (T<sub>C</sub> = 25°C unless otherwise noted)

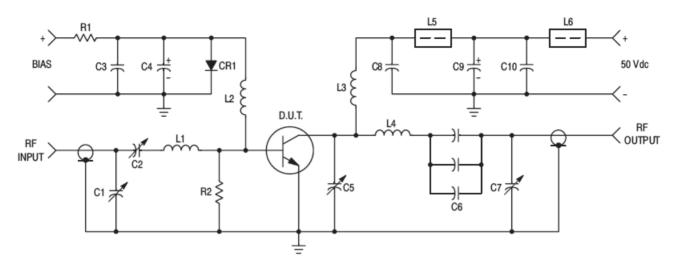
Characteristic	Symbol	Min.	Тур.	Max.	Unit
ON CHARACTERISTICS					
DC Current Gain (I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 10 Vdc)	h <sub>FE</sub>	25	_	50	_
DYNAMIC CHARACTERISTICS					
Output Capacitance $(V_{CB} = 50 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>ob</sub>	_	350	450	pF
FUNCTIONAL TESTS					
Common-Emitter Amplifier Power Gain (V <sub>CC</sub> = 50 Vdc, P <sub>out</sub> = 250 W CW, f = 30 MHz, I <sub>CQ</sub> =250 mA)	G <sub>PE</sub>	12	14	_	dB
Collector Efficiency (V <sub>CC</sub> = 50 Vdc, P <sub>out</sub> = 250 W, f = 30 MHz, I <sub>CQ</sub> = 250 mA)	η	_ _	45 65	_	% (PEP) % (CW)
Intermodulation Distortion (2) (V <sub>CE</sub> = 50 Vdc, P <sub>out</sub> = 250 W (PEP), I <sub>CQ</sub> = 250mA, f = 30 MHz)	IMD	_	-33	-30	dB
Electrical Ruggedness (V <sub>CC</sub> = 50 Vdc, P <sub>out</sub> = 250 W CW, f =30 MHz, VSWR 3:1 at all Phases Angles)	Ψ	No Degradation in Output Power			

Note:

<sup>2.</sup> To Mil-Std-1311 Version A, Test Method 2204, Two Tone, Reference Each Tone



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C1, C2, C5, C7 — 170–780 pF, Arco 469 C3, C8, C9 — 0.1  $\mu\text{F}$ , 100 V Erie

C4 — 500 μF @ 6.0 V

C6 — 360 pF, 3 x 120 pF 3.0 kV in parallel

C10 - 10 µF, 100 V

R1 —  $10 \Omega$ , 10 Watt

R2 - 10 Ω, 1.0 Watt

CR1 - 1N4997 or equivalent

L1 - 3 Turns, #16 Wire, 0.4" I.D., 0.3" Long

L2 - 0.8 μH, Ohmite Z-235 or equivalent

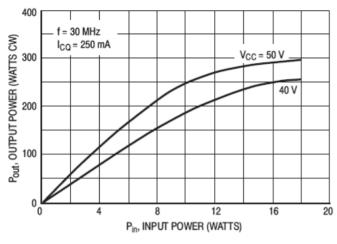
L3 — 12 Turns, #16 Enameled Wire Closewound 0.25" I.D.

L4 — 4 Turns, 1/8" Copper Tubing, 0.6" I.D., 1.0" Long

L5, L6 — 2.0 μH, Fair-Rite 2643021801 Ferrite bead each or equivalent

Figure 1. 30 MHz Test Circuit Schematic





400

f = 30, 30.001 MHz

I<sub>CQ</sub> = 250 mA

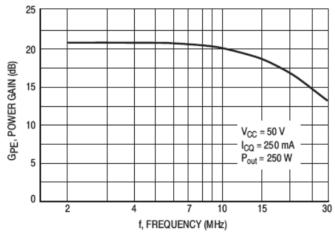
IMD = -30 dB

-35 dB

V<sub>CC</sub>, SUPPLY VOLTAGE (VOLTS)

Figure 2. Output Power versus Input Power

Figure 3. Output Power versus Supply Voltage



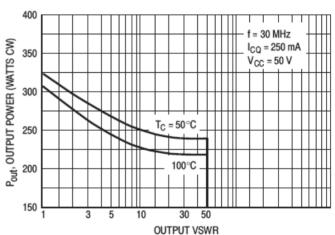


Figure 4. Power Gain versus Frequency

Figure 5. RF SOAR (Class AB)
Pout versus Output VSWR



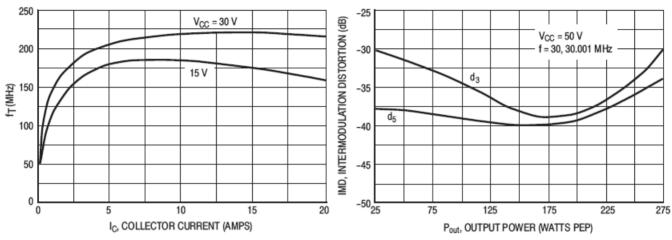


Figure 6. f<sub>T</sub> versus Collector Current

Figure 7. IMD versus Pout



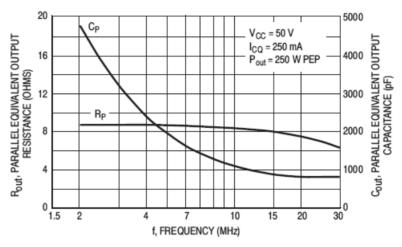
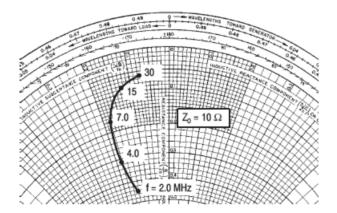


Figure 8. Output Resistance and Capacitance versus Frequency

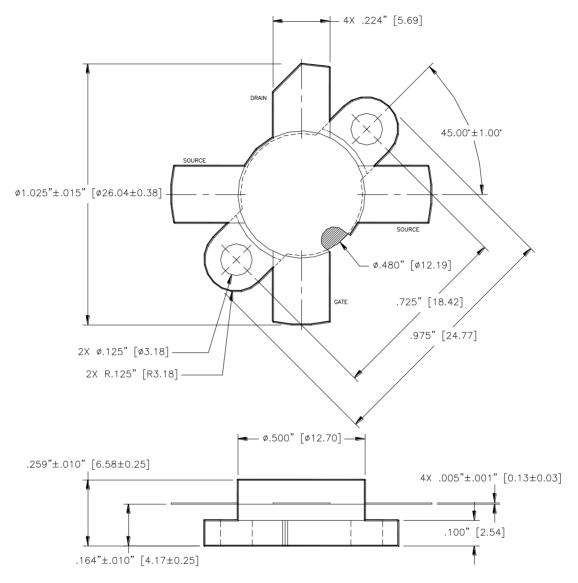


 $V_{CC}$  = 50 V  $I_{CQ}$  = 150 mA  $P_{out}$  = 250 W PEP

f MHz	Z <sub>in</sub> Ohms
2.0	4.50 - j1.40
4.0	3.10 - j1.80
7.0	1.70 - j1.75
15	0.80 - j1.25
30	0.60 - j0.75

Figure 9. Series Equivalent Impedance





Unless otherwise noted, tolerances are inches  $\pm .005$ " [millimeters  $\pm 0.13$ mm]

## MRF448A



The RF Line NPN Silicon Power Transistor 250 W, 30 MHz, 50 V

Rev. V1

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